NSN 5961-01-017-5452

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-017-5452 **Inclosure Material:** Metal **Overall Length:** 0.297 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pnp **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -350.0 collector to base voltage/static/emitter open and -300.0 collector to emitter voltage/static/base open and -6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 35.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No